

Bipolar Transistor

(-)30 V, (-)3 A, Low V_{CE}(sat) Complementary Dual MCPH6

MCH6541

Features

- Composite Type with a PNP Transistor and an NPN Transistor Contained in One Package Facilitating High-density Mounting
- Ultrasmall Package Permitting Applied Sets to be Small and Slim
- These Devices are Pb-Free and are RoHS Compliant

Applications

- MOSFET Gate Drivers
- Relay Drivers
- Lamp Drivers
- Motor Drivers

Specifications

• (): PNP

ABSOLUTE MAXIMUM RATINGS at $T_A = 25$ °C

Parameter	Symbol	Conditions	Value	Unit
Collector-to-Base Voltage	V _{CBO}		(-30)40	V
Collector-to-Emitter Voltage	V _{CEO}		(-)30	V
Emitter-to-Base Voltage	V _{EBO}		(–)5	V
Collector Current	I _C		(-)700	mA
Collector Current (Pulse)	I _{CP}		(-)3	Α
Collector Dissipation	P _C	When mounted on ceramic substrate (600 mm ² x 0.8 mm) 1 unit	0.5	W
Total Power Dissipation	P _T	When mounted on ceramic substrate (600 mm ² x 0.8 mm)	0.55	W
Junction Temperature	T_{J}		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



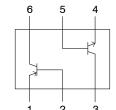
SC-88FL / MCPH6 CASE 419AS

MARKING DIAGRAM



EP = Specific Device Code

ELECTRICAL CONNECTION



- 1 : Emitter1 (PNP TR)
- 2: Base1 (PNP TR)
- 3: Collector2 (NPN TR)
- 4 : Emitter2 (NPN TR)
- 5 : Base2 (NPN TR)
- 6: Collector1 (PNP TR)

ORDERING INFORMATION

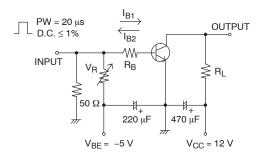
Device	Package	Shipping [†]
MCH6541-TL-E	MCPH6 / SC-88FL (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$

			Ratings			
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} = (-)30 V, I _E = 0 A	_	-	(-)100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} = (-)4 V, I _C = 0 A	-	-	(-)100	nA
DC Current Gain	h _{FE}	V _{CE} = (-)2 V, I _C = (-10)50 mA	(200) 300	-	(500) 800	
Gain-Bandwidth Product	f _T	V _{CE} = (-)2 V, I _C = (-)50 mA	_	(520) 540	-	MHz
Output Capacitance	Cob	V _{CB} = (-)10 V, f = 1 MHz	_	(4.7) 3.3	-	pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = (-)200 mA, I _B = (-)10 mA	_	(-110) 85	(-220) 190	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C = (-)200 mA, I _B = (-)10 mA	_	(-)0.9	(-)1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C = (-)10 μA, I _E = 0 A	(-30) 40	-	-	V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C = (-)1 mA, R _{BE} = ∞	(-)30	-	-	V
Emitter-to-Base Breakdown Voltage	V(_{BR}) _{EBO}	I _E = (-)10 μA, I _C = 0 A	(–)5	-	-	V
Turn-On Time	t _{on}	See specified Test Circuit	_	35	-	ns
Storage Time	t _{stg}		_	(125) 255	-	ns
Fall Time	t _f		-	(25) 40	-	ns

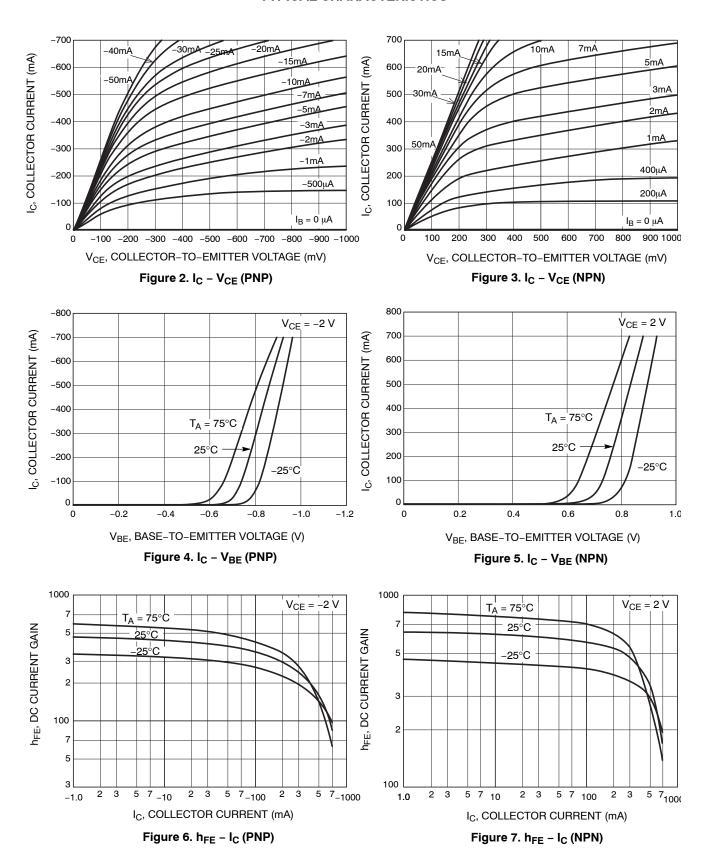
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



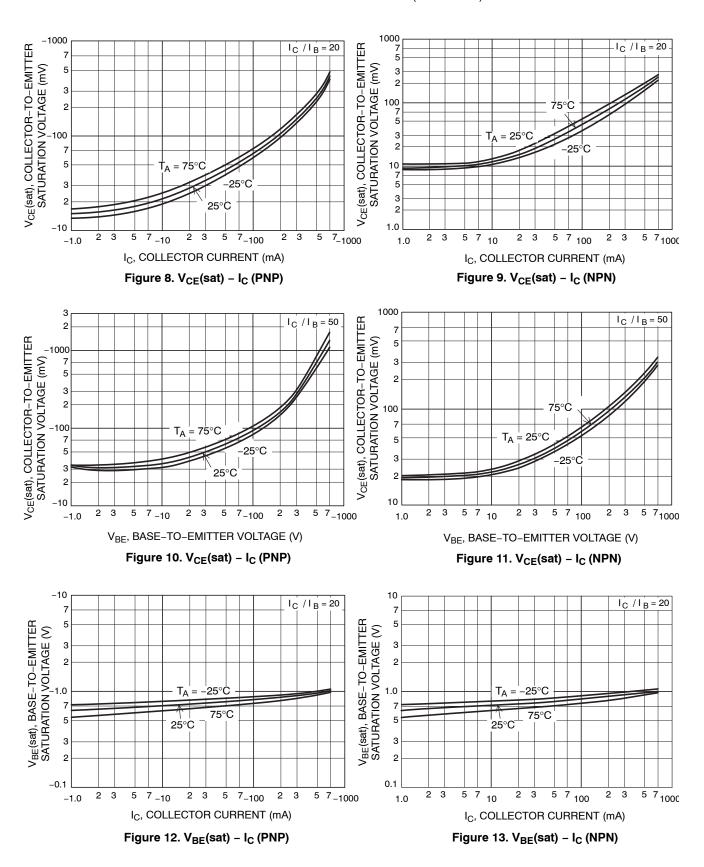
 I_C = 20 I_{B1} = -20 I_{B2} = 300 mA For PNP, the polarity is reversed.

Figure 1. Switching Time Test Circuit

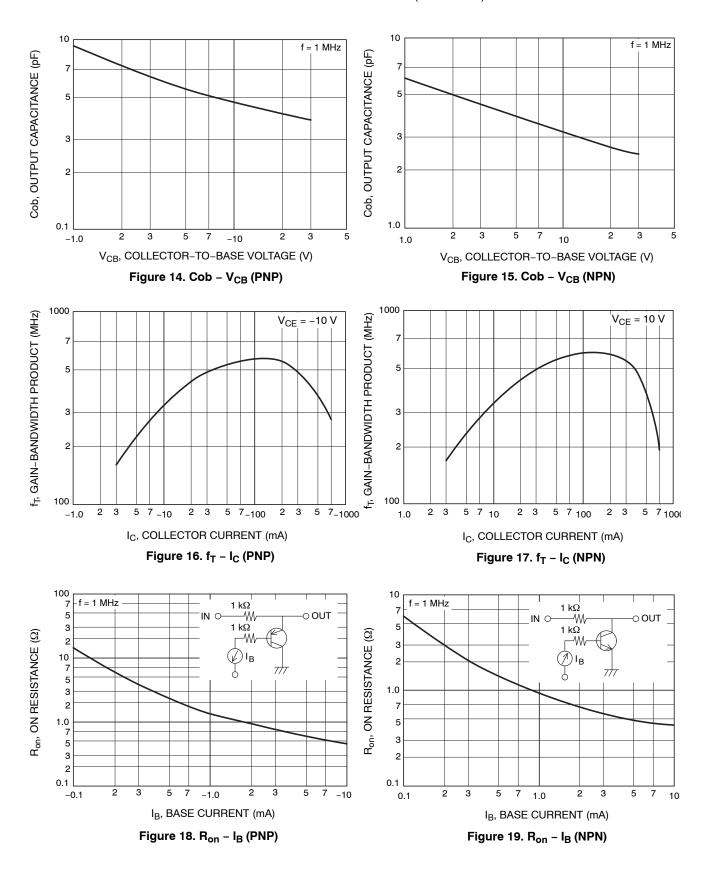
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (CONTINUED)



TYPICAL CHARACTERISTICS (CONTINUED)



TYPICAL CHARACTERISTICS (CONTINUED)

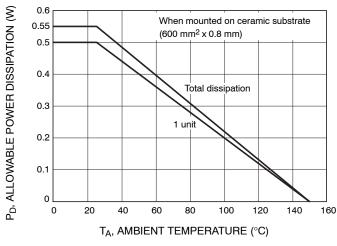


Figure 20. P_D – T_A (PNP/NPN)

LAND PATTERN EXAMPLE

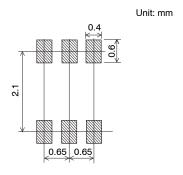


Figure 21. Land Pattern Example

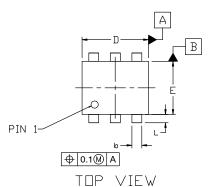


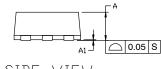


SC-88FL / MCPH6 CASE 419AS **ISSUE A**

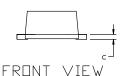
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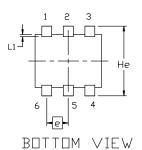












NOTES:

- NO INDUSTRY STANDARD APPLIES TO THIS PACKAGE.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND THE BAR PROTRUSIONS.

DIM	MILLIMETERS			
	MIN.	N□M.	MAX.	
Α	0.80	0.85	0.90	
A1	0.00		0.02	
b	0.25	0.30	0.40	
C	0.12	0.15	0.25	
D	1.94	2.00	2.06	
Е	1.54	1.60	1.66	
He	2.05	2.10	2.15	
L	0.19	0.25	0.31	
L1	0.00	0.07	0.12	
е	0.65 BSC			

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code М = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	SC-88FL / MCPH6		PAGE 1 OF 1	

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